

BZX97/C3V9 Chenyi Electronics Silicon Planar Zener Diode. 0.5 W. Zener voltage range Vznom = 3.9 V, Izt = 5 mA for Vz.

BZX97/C3V9 Chenyi Electronics Silicon Planar Zener Diode. 0.5 W. Zener voltage range Vznom = 3.9 V, Izt = 5 mA for Vz.

BAT754,215 NXP Semiconductors / Philips Semiconductors Schottky barrier (double) diodes - Cd max.: 10@VR=1V pF; Configuration: single ; IF max: 200 mA; IFSM max: 600 A; IR max: 2@VR=25VA; VFmax: 340@IF=10mA mV; VR max: 30 V; Package: SOT23 (TO-236AB); Container: Tape reel smd

BAT754A,215 NXP Semiconductors / Philips Semiconductors Schottky barrier (double) diodes - Cd max.: 10@VR=1V pF; Configuration: dual c.a. ; IF max: 200 mA; IFSM max: 600 A; IR max: 2@VR=25VA; VFmax: 340@IF=10mA mV; VR max: 30 V; Package: SOT23 (TO-236AB); Container: Tape reel smd

BAT754AT/R NXP Semiconductors / Philips Semiconductors Schottky barrier (double) diodes - Cd max.: 10@VR=1V pF; Configuration: dual c.a. ; IF max: 200 mA; IFSM max: 600 A; IR max: 2@VR=25VA; VFmax: 340@IF=10mA mV; VR max: 30 V

BAT754A Philips Semiconductors / NXP Semiconductors Schottky barrier double diodes

BAT754AT NXP Semiconductors / Philips Semiconductors DIODE SCHOTTKY 30V 0.2A

BAT754AT/R NXP Semiconductors / Philips Semiconductors Schottky barrier (double) diodes - Cd max.: 10@VR=1V pF; Configuration: dual c.a. ; IF max: 200 mA; IFSM max: 600 A; IR max: 2@VR=25VA; VFmax: 340@IF=10mA mV; VR max: 30 V

BAT754C Philips Semiconductors / NXP Semiconductors Schottky Barrier Double Diodes

BAT754C,215 NXP Semiconductors / Philips Semiconductors Schottky barrier (double) diodes - Cd max.: 10@VR=1V pF; Configuration: dual c.c. ; IF max: 200 mA; IFSM max: 600 A; IR max: 2@VR=25VA; VFmax: 340@IF=10mA mV; VR max: 30 V; Package: SOT23 (TO-236AB); Container: Tape reel smd

BAT754CT/R NXP Semiconductors / Philips Semiconductors Schottky barrier (double) diodes - Cd max.: 10@VR=1V pF; Configuration: dual c.c. ; IF max: 200 mA; IFSM max: 600 A; IR max: 2@VR=25VA; VFmax: 340@IF=10mA mV; VR max: 30 V

BAT754CT NXP Semiconductors / Philips Semiconductors DIODE SCHOTTKY 30V 0.2A

BAT754CT/R NXP Semiconductors / Philips Semiconductors Schottky barrier (double) diodes - Cd max.: 10@VR=1V pF; Configuration: dual c.c. ; IF max: 200 mA; IFSM max: 600 A; IR max: 2@VR=25VA; VFmax: 340@IF=10mA mV; VR max: 30 V

BAT754LT/R NXP Semiconductors / Philips Semiconductors Schottky barrier triple diode - Cd max.: 10@VR=1V pF; Configuration: triple isolated ; IF max: 200 mA; IFSM max: 600 A; IR max: 2@VR=25VA; VFmax: 340@IF=10mA mV; VR max: 30 V

BAT754L Philips Semiconductors / NXP Semiconductors Schottky barrier triple diode

BAT754S Philips Semiconductors / NXP Semiconductors Schottky barrier double diodes

BAT754S,215 NXP Semiconductors / Philips Semiconductors Schottky barrier (double) diodes - Cd max.: 10@VR=1V pF; Configuration: dual series ; IF max: 200 mA; IFSM max: 600 A; IR max: 2@VR=25VA; VFmax: 340@IF=10mA mV; VR max: 30 V; Package: SOT23 (TO-236AB); Container: Tape reel smd

BAT754L,115 NXP Semiconductors / Philips Semiconductors Schottky barrier triple diode - Cd max.: 10@VR=1V pF; Configuration: triple isolated ; IF max: 200 mA; IFSM max: 600 A; IR max: 2@VR=25VA; VFmax: 340@IF=10mA mV; VR max: 30 V; Package: SOT363 (SC-88); Container: Tape reel smd

BAT754ST NXP Semiconductors / Philips Semiconductors DIODE SCHOTTKY 30V 0.2A

BAT754ST/R NXP Semiconductors / Philips Semiconductors DIODE SCHOTTKY 30V 0.2A

BAT754T NXP Semiconductors / Philips Semiconductors DIODE SCHOTTKY 30V 0.2A

BAT754ST/R NXP Semiconductors / Philips Semiconductors DIODE SCHOTTKY 30V 0.2A

BAT754T/R NXP Semiconductors / Philips Semiconductors Schottky barrier (double) diodes - Cd max.: 10@VR=1V pF; Configuration: single ; IF max: 200 mA; IFSM max: 600 A; IR max: 2@VR=25VA; VFmax: 340@IF=10mA mV; VR max: 30 V

BAT754T/R NXP Semiconductors / Philips Semiconductors Schottky barrier (double) diodes - Cd max.: 10@VR=1V pF; Configuration: single ; IF max: 200 mA; IFSM max: 600 A; IR max: 2@VR=25VA; VFmax: 340@IF=10mA mV; VR max: 30 V

BAT760,115 NXP Semiconductors / Philips Semiconductors Schottky barrier diode - Cd max.: 25@VR=5V pF; Configuration: single ; IF: 1 A; IFSM max: 5 A; IR max: 0.05@VR=15V mA; VFmax: 550@IF=1A mV; VR: 20 V; Package: SOD323 (UMD2; I-IEIA; URP); Container: Tape reel smd

BAT760T NXP Semiconductors / Philips Semiconductors DIODE SCHOTTKY 20V 1A 2

BAT81 EIC Semiconductor, Inc. Schottky Barrier Diodes

BAT760 Philips Semiconductors / NXP Semiconductors Schottky barrier diode

BAT81S Taitron Components Rectifier Diode, Schottky Diode, Single, 40 MinV, SOD-27, 2-Pin

BAT760-7 Diodes, Inc. RECTIFIER SCHOTTKY SINGLE 1A 15V 5.5A-I fsm 0.55Vf 0.05A-IR SOD-323 3K/REEL

BAT760T/R NXP Semiconductors / Philips Semiconductors Schottky barrier diode - Cd max.: 25@VR=5V pF; Configuration: single ; IF: 1 A; IFSM max: 5 A; IR max: 0.05@VR=15V mA; VFmax: 550@IF=1A mV; VR: 20 V

BAT81-A52R Philips Semiconductors / NXP Semiconductors Schottky barrier diodes

BAT81S-TR Vishay DIODE SCHOTTKY 40V 0.03A

BAT81T/R NXP Semiconductors / Philips Semiconductors DIODE SCHOTTKY 40V 0.03A

BAT81S-TAP Vishay DIODE SCHOTTKY 40V 0.03A

BAT82S-TAP Vishay DIODE SCHOTTKY 50V 0.03A

BAT82 EIC Semiconductor, Inc. Schottky Barrier Diodes

BAT82S Taitron Components Rectifier Diode, Schottky Diode, Single, 50 MinV, SOD-27, 2-Pin

BAT83 EIC Semiconductor, Inc. Schottky Barrier Diodes

BAT83-A52R Philips Semiconductors / NXP Semiconductors Schottky barrier diodes

BAT82S-TR Vishay DIODE SCHOTTKY 50V 0.03A

BAT83S-TAP Vishay DIODE SCHOTTKY 60V 0.03A

BAT83S Taitron Components Rectifier Diode, Schottky Diode, Single, 60 MinV, SOD-27, 2-Pin

BAT83S-TR Vishay DIODE SCHOTTKY 60V 0.03A

BAT83T NXP Semiconductors / Philips Semiconductors DIODE SCHOTTKY 60V 0.03A

BAT83T/R NXP Semiconductors / Philips Semiconductors DIODE SCHOTTKY 60V 0.03A

BAT84 Taitron Components Rectifier Diode, Schottky Diode, Single, 40 MinV, SOD-27, 2-Pin

BAT85 Spice Vishay BAT85 Spice Parameters

BAT85,113 NXP Semiconductors / Philips Semiconductors Schottky barrier diode - Cd max.: 10@VR=1V pF; Configuration: single ; IF max: 200 mA; IFSM max: 5000 A; IR max: 2@VR=25VA; VFmax: 400@IF=10mA mV; VR max: 30 V; Package: SOD68 (DO-34); Container: Reel pack axial radial

BAT854AW,115 NXP Semiconductors / Philips Semiconductors Schottky barrier (double) diodes - Cd max.: 20@VR=1V pF; Configuration: dual c.a. ; IF max: 200 mA; IFSM max: 1000 A; IR max: 0.5@VR=25VA; VFmax: 420@IF=10mA mV; VR max: 40 V; Package: SOT323 (SC-70); Container: Tape reel smd

BAT854AWT/R NXP Semiconductors / Philips Semiconductors Schottky barrier (double) diodes - Cd max.: 20@VR=1V pF; Configuration: dual c.a. ; IF max: 200 mA; IFSM max: 1000 A; IR max: 0.5@VR=25VA; VFmax: 420@IF=10mA mV; VR max: 40 V

BAT854CW Philips Semiconductors / NXP Semiconductors Schottky barrier (double) diodes

BAT854CW,135 NXP Semiconductors / Philips Semiconductors Schottky barrier (double) diodes - Cd max.: 20@VR=1V pF; Configuration: dual c.c. ; IF max: 200 mA; IFSM max: 1000 A; IR max: 0.5@VR=25VA; VFmax: 420@IF=10mA mV; VR max: 40 V; Package: SOT323 (SC-70); Container: Tape reel smd

BAT854CWT/R NXP Semiconductors / Philips Semiconductors Schottky barrier (double) diodes - Cd max.: 20@VR=1V pF; Configuration: dual c.c. ; IF max: 200 mA; IFSM max: 1000 A; IR max: 0.5@VR=25VA; VFmax: 420@IF=10mA mV; VR max: 40 V

BAT854SW Philips Semiconductors / NXP Semiconductors Schottky barrier (double) diodes

BAT854SW,115 NXP Semiconductors / Philips Semiconductors Schottky barrier (double) diodes - Cd max.: 20@VR=1V pF; Configuration: dual series ; IF max: 200 mA; IFSM max: 1000 A; IR max: 0.5@VR=25VA; VFmax: 420@IF=10mA mV; VR max: 40 V; Package: SOT323 (SC-70); Container: Tape reel smd

BAT85 EIC Semiconductor, Inc. Schottky Barrier Diodes

BAT85,133 NXP Semiconductors / Philips Semiconductors Schottky barrier diode - Cd max.: 10@VR=1V pF; Configuration: single ; IF max: 200 mA; IFSM max: 5000 A; IR max: 2@VR=25VA; VFmax: 400@IF=10mA mV; VR max: 30 V; Package: SOD68 (DO-34); Container: Ammo pack axial radial taped

BAT854SWT NXP Semiconductors / Philips Semiconductors DIODE SCHOTTKY 40V 0.2A

BAT854AW Philips Semiconductors / NXP Semiconductors Schottky barrier (double) diodes

BAT854AWT/R NXP Semiconductors / Philips Semiconductors Schottky barrier (double) diodes - Cd max.: 20@VR=1V pF; Configuration: dual c.a. ; IF max: 200 mA; IFSM max: 1000 A; IR max: 0.5@VR=25VA; VFmax: 420@IF=10mA mV; VR max: 40 V

BAT854SWT/R NXP Semiconductors / Philips Semiconductors Schottky barrier (double) diodes - Cd max.: 20@VR=1V pF; Configuration: dual series ; IF max: 200 mA; IFSM max: 1000 A; IR max: 0.5@VR=25VA; VFmax: 420@IF=10mA mV; VR max: 40 V

BAT854CW,115 NXP Semiconductors / Philips Semiconductors Schottky barrier (double) diodes - Cd max.: 20@VR=1V pF; Configuration: dual c.c. ; IF max: 200 mA; IFSM max: 1000 A; IR max: 0.5@VR=25VA; VFmax: 420@IF=10mA mV; VR max: 40 V; Package: SOT323 (SC-70); Container: Tape reel smd

BAT854WT/R NXP Semiconductors / Philips Semiconductors Schottky barrier (double) diodes - Cd max.: 20@VR=1V pF; Configuration: single ; IF max: 200 mA; IFSM max: 1000 A; IR max: 0.5@VR=25VA; VFmax: 420@IF=10mA mV; VR max: 40 V

BAT854SWT/R NXP Semiconductors / Philips Semiconductors Schottky barrier (double) diodes - Cd max.: 20@VR=1V pF; Configuration: dual series ; IF max: 200 mA; IFSM max: 1000 A; IR max: 0.5@VR=25VA; VFmax: 420@IF=10mA mV; VR max: 40 V

BAT85-D7 Vishay DIODE SCHOTTKY 30V

BAT854W Philips Semiconductors / NXP Semiconductors Schottky barrier (double) diodes

BAT854W,115 NXP Semiconductors / Philips Semiconductors Schottky barrier (double) diodes - Cd max.: 20@VR=1V pF; Configuration: single ; IF max: 200 mA; IFSM max: 1000 A; IR max: 0.5@VR=25VA; VFmax: 420@IF=10mA mV; VR max: 40 V; Package: SOT323 (SC-70); Container: Tape reel smd

BAT85-A52R Philips Semiconductors / NXP Semiconductors Schottky barrier diode

BAT85S Taitron Components Rectifier Diode, Schottky Diode, Single, 30 MinV, SOD-27, 2-Pin

BAT85S-TR Vishay DIODE SCHOTTKY 30V 0.2A

BAT85T/R NXP Semiconductors / Philips Semiconductors DIODE SCHOTTKY 30V 0.2A

BAT85S-TAP Vishay DIODE SCHOTTKY 30V 0.2A

BAT86,113 NXP Semiconductors / Philips Semiconductors Schottky barrier diode - Cd max.: 8@VR=1V pF; Configuration: single ; IF max: 200 mA; IFSM max: 5000 A; IR max: 5@VR=40VA; VFmax: 450@IF=10mA mV; VR max: 50 V; Package: SOD68 (DO-34); Container: Reel pack axial radial

BAT85T NXP Semiconductors / Philips Semiconductors DIODE SCHOTTKY 30V 0.2A

BAT86,133 NXP Semiconductors / Philips Semiconductors Schottky barrier diode - Cd max.: 8@VR=1V pF; Configuration: single ; IF max: 200 mA; IFSM max: 5000 A; IR max: 5@VR=40VA; VFmax: 450@IF=10mA mV; VR max: 50 V; Package: SOD68 (DO-34); Container: Ammo pack axial radial taped

BAT86-A52A Philips Semiconductors / NXP Semiconductors Schottky barrier diode

BAT85T/R NXP Semiconductors / Philips Semiconductors DIODE SCHOTTKY 30V 0.2A

BAT86S-TAP Vishay Intertechnology, Inc. Small Signal Schottky Barrier Diode

BAT86S-TR Vishay Intertechnology, Inc. Small Signal Schottky Barrier Diode

BAT93 Philips Semiconductors / NXP Semiconductors Schottky barrier diode

BAT960,115 NXP Semiconductors / Philips Semiconductors Schottky barrier diode - Cd max.: 25@VR=5V pF; Configuration: single ; IF: 1 A; IFSM max: 8 A; IR max: 0.05@VR=15V mA; VFmax: 550@IF=1A mV; VR: 20 V; Package: SOT666 (SS-Mini); Container: Tape reel smd

BAT960T/R NXP Semiconductors / Philips Semiconductors Schottky barrier diode - Cd max.: 25@VR=5V pF; Configuration: single ; IF: 1 A; IFSM max: 8 A; IR max: 0.05@VR=15V mA; VFmax: 550@IF=1A mV; VR: 20 V

BAT86 EIC Semiconductor, Inc. Schottky Barrier Diodes

BAT86S Taitron Components Rectifier Diode, Schottky Diode, Single, 50 MinV, SOD-27, 2-Pin

BAT86T/R NXP Semiconductors / Philips Semiconductors Schottky barrier diode - Cd max.: 8@VR=1V pF; Configuration: single ; IF max: 200 mA; IFSM max: 5000 A; IR max: 5@VR=40VA; VFmax: 450@IF=10mA mV; VR max: 50 V

BAT960 Philips Semiconductors / NXP Semiconductors Schottky barrier diode

Battery Guide Seiko Instruments, Inc. Micro Batteries Product Catalog

BATMOD Vicor Corporation Battery Charger Current Source Modules

BAV100GS18 Vishay DIODE SWITCHING 60V 0.25A 2SOD-80 T/R

BAV100GS18 Vishay DIODE SWITCHING 60V 0.25A 2SOD-80 T/R

BAV100T/R Philips Semiconductors / NXP Semiconductors DIODE SWITCHING 60V 0.25A 2SOD-80C T/R

BAV10 EIC Semiconductor, Inc. High Speed Switching Diodes

BAV100T/R Philips Semiconductors / NXP Semiconductors DIODE SWITCHING 60V 0.25A 2SOD-80C T/R

BAV101/T3 Philips Semiconductors / NXP Semiconductors DIODE SWITCHING 120V 0.25A 2SOD-80C T/R

BAV101-7 Diodes, Inc. DIODE ULTRA FAST RECOVERY RECTIFIER 250V 0.125A 2MINIMELF T/R

BAV101-GS08 Vishay DIODE SWITCHING 120V 0.25A 2SOD-80 T/R

BAV101-GS18 General Semiconductor, Inc. DIODE ULTRA FAST RECOVERY RECTIFIER 120V 0.25A 2SOD-80 T/R

BAV100 BKC International MELF High Voltage Switching Diodes

BAV100/T3 Philips Semiconductors / NXP Semiconductors DIODE SWITCHING 60V 0.25A 2SOD-80C T/R

BAV100-GS08 Vishay DIODE SWITCHING 60V 0.25A 2SOD-80 T/R

BAV102 BKC International MELF High Voltage Switching Diodes

BAV102,115 NXP Semiconductors / Philips Semiconductors Single general-purpose switching diodes - Cd max.: 5 pF; Configuration: single ; IF max: 250 mA; IFSM max: 9 A; IR max: 100@VR=150V nA; IFRM: 625 mA; trr max: 50 ns; VFmax: 1@IF=100mA mV; VR max: 150 V; Package: SOD80C (LLDS; MiniMelf); Container: Tape reel smd

BAV102,135 NXP Semiconductors / Philips Semiconductors Single general-purpose switching diodes - Cd max.: 5 pF; Configuration: single ; IF max: 250 mA; IFSM max: 9 A; IR max: 100@VR=150V nA; IFRM: 625 mA; trr max: 50 ns; VFmax: 1@IF=100mA mV; VR max: 150 V; Package: SOD80C (LLDS; MiniMelf); Container: Tape reel smd

BAV102/T3 Philips Semiconductors / NXP Semiconductors DIODE SWITCHING 200V 0.25A 2SOD-80C T/R

BAV102_D87Z Fairchild Semiconductor DIODE STANDARD RECOVERY RECTIFIER 200V 0.2A 2LL-34 T/R

BAV102T/R NXP Semiconductors / Philips Semiconductors Single general-purpose switching diodes - Cd max.: 5 pF; Configuration: single ; IF max: 250 mA; IFSM max: 9 A; IR max: 100@VR=150V nA; IFRM: 625 mA; trr max: 50 ns; VFmax: 1@IF=100mA mV; VR max: 150 V

BAV102-TPTR Micro Commercial Components DIODE ULTRA FAST RECOVERY RECTIFIER 200V 0.2A 2MINIMELF T/R

BAV102T/R NXP Semiconductors / Philips Semiconductors Single general-purpose switching diodes - Cd max.: 5 pF; Configuration: single ; IF max: 250 mA; IFSM max: 9 A; IR max: 100@VR=150V nA; IFRM: 625 mA; trr max: 50 ns; VFmax: 1@IF=100mA mV; VR max: 150 V

BAV101 BKC International MELF High Voltage Switching Diodes

BAV101T/R Philips Semiconductors / NXP Semiconductors DIODE SWITCHING 120V 0.25A 2SOD-80C T/R

BAV102_NL Fairchild Semiconductor DIODE ULTRA FAST RECOVERY RECTIFIER 200V

BAV102-GS08 Vishay DIODE SWITCHING 200V 0.25A 2SOD-80 T/R

BAV102-GS18 General Semiconductor, Inc. DIODE ULTRA FAST RECOVERY RECTIFIER 200V 0.25A 2SOD-80 T/R

BAV103-GS18 Vishay DIODE SWITCHING 250V 0.25A 2SOD-80 T/R

BAV103T/R NXP Semiconductors / Philips Semiconductors Single general-purpose switching diodes - Cd max.: 5 pF; Configuration: single ; IF max: 250 mA; IFSM max: 9 A; IR max: 100@VR=200V nA; IFRM: 625 mA; trr max: 50 ns; VFmax: 1@IF=100mA mV; VR max: 200 V

BAV103T/R NXP Semiconductors / Philips Semiconductors Single general-purpose switching diodes - Cd max.: 5 pF; Configuration: single ; IF max: 250 mA; IFSM max: 9 A; IR max: 100@VR=200V nA; IFRM: 625 mA; trr max: 50 ns; VFmax: 1@IF=100mA mV; VR max: 200 V

BAV103 BKC International MELF High Voltage Switching Diodes

BAV103,115 NXP Semiconductors / Philips Semiconductors Single general-purpose switching diodes - Cd max.: 5 pF; Configuration: single ; IF max: 250 mA; IFSM max: 9 A; IR max: 100@VR=200V nA; IFRM: 625 mA; trr max: 50 ns; VFmax: 1@IF=100mA mV; VR max: 200 V; Package: SOD80C (LLDS; MiniMelf); Container: Tape reel smd

BAV103,135 NXP Semiconductors / Philips Semiconductors Single general-purpose switching diodes - Cd max.: 5 pF; Configuration: single ; IF max: 250 mA; IFSM max: 9 A; IR max: 100@VR=200V nA; IFRM: 625 mA; trr max: 50 ns; VFmax: 1@IF=100mA mV; VR max: 200 V; Package: SOD80C (LLDS; MiniMelf); Container: Tape reel smd

BAV103_NL Fairchild Semiconductor DIODE ULTRA FAST RECOVERY RECTIFIER 250V 0.2

BAV105 EIC Semiconductor, Inc. High Speed Switching Diodes

BAV10-A52R Philips Semiconductors / NXP Semiconductors High-speed diode

BAV116-7 Diodes, Inc. SURFACE MOUNT LOW LEAKAGE DIODE

BAV103-GS08 General Semiconductor, Inc. DIODE ULTRA FAST RECOVERY RECTIFIER 250V 0.25A 2SOD-80 T/R

BAV116T Diodes, Inc. SURFACE MOUNT LOW LEAKAGE DIODE

BAV116W-7 Diodes, Inc. Surface Mount Low Leakage Diode

BAV116W Diodes, Inc. SURFACE MOUNT LOW LEAKAGE DIODE

BAV116W-7-F Diodes, Inc. DIODE SWITCHING SINGLE 75V 215mA-Io 250mW 3000ns-trr SOD-123 3K/REEL

BAV16 PanJit Semiconductors SURFACE MOUNT SWITCHING DIODES

BAV16W-7 Diodes, Inc. SURFACE MOUNT FAST SWITCHING DIODE

BAV16W-7-F Diodes, Inc. DIODE SWITCH 75V 400MW SOD123

BAV16W Diodes, Inc. SURFACE MOUNT FAST SWITCHING DIODE

BAV16WS Diodes, Inc. SURFACE MOUNT FAST SWITCHING DIODE

BAV16WS-7 Diodes, Inc. Surface Mount Fast Switching Diode

BAV16WS-7-F Diodes, Inc. DIODE SWITCHING SINGLE 75V 150mA-Io 200mW 4ns-trr SOD-323 3K/REEL

BAV16WS-T3 Won-Top Electronics SURFACE MOUNT FAST SWITCHING DIODE

BAV16WS-T1 Won-Top Electronics SURFACE MOUNT FAST SWITCHING DIODE

BAV16W-T3 Won-Top Electronics SURFACE MOUNT FAST SWITCHING DIODE

BAV16W-T1 Won-Top Electronics SURFACE MOUNT FAST SWITCHING DIODE

BAV17 BKC International 25 V, 400 mW silicon epitaxial planar diode

BAV170,215 NXP Semiconductors / Philips Semiconductors Low-leakage double diode - Cd max.: 2 pF; Configuration: dual c.c. ; IF max: 215 mA; IFSM max: 4 A; IR max: 5@VR=75V nA; IFRM: 500 mA; trr max: 3000 ns; VFmax: 1@IF=10mA mV; VR max: 75 V; Package: SOT23 (TO-236AB); Container: Tape reel smd

BAV170 Diodes, Inc. Introducing Very Low Leakage SOT-23 Diodes:

BAV170-F Diodes, Inc. DIODE SWITCH 85V 250MW SMD SOT23

BAV170T/R NXP Semiconductors / Philips Semiconductors Low-leakage double diode - Cd max.: 2 pF; Configuration: dual c.c. ; IF max: 215 mA; IFSM max: 4 A; IR max: 5@VR=75V nA; IFRM: 500 mA; trr max: 3000 ns; VFmax: 1@IF=10mA mV; VR max: 75 V

BAV170-7-F Diodes, Inc. DUAL SURFACE MOUNT LOW LEAKAGE DIODE

BAV170T-7-F Diodes, Inc. DIODE SWITCHING DUAL COMMON-CATHODE 75V 215mA-Io 150mW 3000ns-trr SOT-523 3K/REEL

BAV170W PanJit Semiconductors SURFACE MOUNT, LOW LEAKAGE SWITCHING DIODES

BAV170LT1 Leshan Radio Company Co., Ltd. Monolithic Dual Switching Diode

BAV17-TAP Vishay Intertechnology, Inc. Switching Diode
 BAV170T Diodes, Inc. SURFACE MOUNT LOW LEAKAGE DIODE
 BAV170T-7 Diodes, Inc. Surface Mount Low Leakage Diode
 BAV17-TR Vishay Intertechnology, Inc. Switching Diode
 BAV18 BKC International 60 V, 400 mW silicon epitaxial planar diode
 BAV18-TAP Vishay Intertechnology, Inc. Switching Diode
 BAV19 BKC International 120 V, 400 mW silicon epitaxial planar diode
 BAV199,235 NXP Semiconductors / Philips Semiconductors Low-leakage double diode - Cd max.: 2 pF; Configuration: dual series ; IF max: 160 mA; IFSM max: 4 A; IR max: 5@VR=75V nA; IFRM: 500 mA; trr max: 3000 ns; VFmax: 1@IF=10mA mV; VR max: 75 V; Package: SOT23 (TO-236AB); Container: Tape reel smd
 BAV199-7-F Diodes, Inc. DIODE SWITCHING DUAL SERIES 75V 160mA-Io 250mW 3000ns-trr SOT-23 3K/REEL
 BAV199 Diodes, Inc. DUAL SURFACE MOUNT LOW LEAKAGE DIODE
 BAV199,215 NXP Semiconductors / Philips Semiconductors Low-leakage double diode - Cd max.: 2 pF; Configuration: dual series ; IF max: 160 mA; IFSM max: 4 A; IR max: 5@VR=75V nA; IFRM: 500 mA; trr max: 3000 ns; VFmax: 1@IF=10mA mV; VR max: 75 V; Package: SOT23 (TO-236AB); Container: Tape reel smd
 BAV199-7 Diodes, Inc. DUAL SURFACE MOUNT LOW LEAKAGE DIODE
 BAV199DW Diodes, Inc. Switching Diodes
 BAV199DW-7-F Diodes, Inc. DIODE SWITCHING DUAL-DUAL SERIES 75V 160mA-Io 200mW 3000ns-trr SOT-363 3K/REEL
 BAV199DW-SOT-363 Jiangsu Changjiang Electronics Technology Co., Ltd. Multi-Chip DIODES
 BAV199DW-7 Diodes, Inc. QUAD SURFACE MOUNT LOW LEAKAGE DIODE
 BAV199F Infineon Technologies Silicon Low Leakage Diode
 BAV199LT1-D On Semiconductor Dual Series Switching Diode
 BAV199LT1G On Semiconductor Small Signal SOT23 Dual Diode 70V Tape and Reel
 BAV199S PanJit Semiconductors SURFACE MOUNT, LOW LEAKAGE SWITCHING DIODES ARRAY
 BAV199L On Semiconductor Dual Series Switching Diode
 BAV199T Diodes, Inc. SURFACE MOUNT LOW LEAKAGE DIODE
 BAV199T-7 Diodes, Inc. Surface Mount Low Leakage Diode
 BAV199LT1 Leshan Radio Company Co., Ltd. 70 V, 215 mA, dual switching diode
 BAV199LT3 On Semiconductor Dual Switching Diode
 BAV199T/R NXP Semiconductors / Philips Semiconductors Low-leakage double diode - Cd max.: 2 pF; Configuration: dual series ; IF max: 160 mA; IFSM max: 4 A; IR max: 5@VR=75V nA; IFRM: 500 mA; trr max: 3000 ns; VFmax: 1@IF=10mA mV; VR max: 75 V
 BAV199W PanJit Semiconductors SURFACE MOUNT, LOW LEAKAGE SWITCHING DIODES
 BAV199T-7-F Diodes, Inc. Surface Mount Low Leakage Diode
 BAV199W,115 NXP Semiconductors / Philips Semiconductors Low-leakage double diode - Cd max.: 2 pF; Configuration: dual series ; IF max: 135 mA; IFSM max: 4 A; IR max: 5@VR=75V nA; IFRM: 500 mA; trr max: 3000 ns; VFmax: 1@IF=10mA mV; VR max: 75 V; Package: SOT323 (SC-70); Container: Tape reel smd
 BAV199WT/R NXP Semiconductors / Philips Semiconductors Low-leakage double diode - Cd max.: 2 pF; Configuration: dual series ; IF max: 135 mA; IFSM max: 4 A; IR max: 5@VR=75V nA; IFRM: 500 mA; trr max: 3000 ns; VFmax: 1@IF=10mA mV; VR max: 75 V
 BAV199W-7 Diodes, Inc. DIODE SWITCHING DUAL SERIES 75V 160mA-Io 200mW 3000ns-trr SOT-323 3K/REEL
 BAV19-TR Vishay Intertechnology, Inc. Switching Diode
 BAV19-TAP Vishay Intertechnology, Inc. Switching Diode
 BAV19W-7 Diodes, Inc. 120V surface mount switching diode. General purpose switching application
 BAV19W-7-F Diodes, Inc. Surface Mount Switching Diode
 BAV19WS-7 Diodes, Inc. SURFACE MOUNT FAST SWITCHING DIODE
 BAV19WS-T1 Won-Top Electronics SURFACE MOUNT FAST SWITCHING DIODE
 BAV19W-T1 Won-Top Electronics SURFACE MOUNT FAST SWITCHING DIODE
 BAV19W Diodes, Inc. Short Form Selection Guide
 BAV19WS Diodes, Inc. Short Form Selection Guide
 BAV20 BKC International 200 V, 400 mW silicon epitaxial planar diode
 BAV20,113 NXP Semiconductors / Philips Semiconductors General purpose diodes - Cd max.: 5 pF; Configuration: single ; IF max: 250 mA; IFSM max: 9 A; IR max: 100@VR=150V nA; IFRM: 625 mA; trr max: 50 ns; VFmax: 1@IF=100mA mV; VR max: 150 V; Package: SOD27 (ALF2); Container: Reel pack axial radial
 BAV19WS-7-F Diodes, Inc. DIODE SWITCHING SINGLE 120V 200mA-Io 200mW 50ns-trr SOD-323 3K/REEL
 BAV20,133 NXP Semiconductors / Philips Semiconductors General purpose diodes - Cd max.: 5 pF; Configuration: single ; IF max: 250 mA; IFSM max: 9 A; IR max: 100@VR=150V nA; IFRM: 625 mA; trr max: 50 ns; VFmax: 1@IF=100mA mV; VR max: 150 V; Package: SOD27 (ALF2); Container: Ammo pack axial radial taped
 BAV19WS-T3 Won-Top Electronics SURFACE MOUNT FAST SWITCHING DIODE
 BAV20,143 NXP Semiconductors / Philips Semiconductors General purpose diodes - Cd max.: 5 pF; Configuration: single ; IF max: 250 mA; IFSM max: 9 A; IR max: 100@VR=150V nA; IFRM: 625 mA; trr max: 50 ns; VFmax: 1@IF=100mA mV; VR max: 150 V; Package: SOD27 (ALF2); Container: Ammo pack axial radial taped
 BAV19W-T3 Won-Top Electronics SURFACE MOUNT FAST SWITCHING DIODE
 BAV20/F3 Vishay DIODE SWITCHING 200V 0
 BAV20_NL Fairchild Semiconductor DIODE ULTRA FAST RECOVERY RECTIFIER 200V 0.2A
 BAV20_T50R Fairchild Semiconductor DIODE ULTRA FAST RECOVERY RECTIFIER 200V 0.2A
 BAV20_T50A Fairchild Semiconductor DIODE ULTRA FAST RECOVERY RECTIFIER 200V 0.2A
 BAV200-GS08 Vishay DIODE SWITCHING 60V 0.25A
 BAV200 GOOD-ARK Electronics Switching Diode
 BAV200-GS18 Vishay DIODE SWITCHING 60V 0.25A
 BAV201 Diodes, Inc. Short Form Selection Guide

BAV201-GS08 Vishay DIODE SWITCHING 120V 0.25A
 BAV202-GS08 Vishay DIODE SWITCHING 200V 0.25A
 BAV202-GS18 Vishay DIODE SWITCHING 200V 0.25A
 BAV203-GS18 Vishay DIODE SWITCHING 250V 0.25A
 BAV202 Diodes, Inc. Short Form Selection Guide
 BAV20-A52R Philips Semiconductors / NXP Semiconductors General purpose diodes
 BAV20-TAP Vishay DIODE SWITCHING 200V 0.625A
 BAV20T/R NXP Semiconductors / Philips Semiconductors DIODE SWITCHING 200V 0.25A
 BAV203 Diodes, Inc. Short Form Selection Guide
 BAV20-T Vishay DIODE SWITCHING 200V 0.625A
 BAV20T/R NXP Semiconductors / Philips Semiconductors DIODE SWITCHING 200V 0.25A
 BAV20T/R NXP Semiconductors / Philips Semiconductors DIODE SWITCHING 200V 0.25A
 BAV20W/D4 Vishay DIODE ULTRA FAST RECOVERY RECTIFIER 150V 200A 2
 BAV20W-G Sensitron Semiconductor DIODE SWITCHING 150V 0.
 BAV20W-GS08 Vishay DIODE ULTRA FAST RECOVERY RECTIFIER 150V 200A 2
 BAV20W Diodes, Inc. SURFACE MOUNT SWITCHING DIODE
 BAV20W/D3 Vishay DIODE ULTRA FAST RECOVERY RECTIFIER 200V 0.2A 2
 BAV20W-7 Diodes, Inc. Surface Mount Switching Diode
 BAV20WS Diodes, Inc. SURFACE MOUNT FAST SWITCHING DIODE
 BAV20W-7-F Diodes, Inc. Surface Mount Switching Diode
 BAV20W-F Diodes, Inc. DIODE SWITCHING 150V 0.
 BAV20W-T1 Won-Top Electronics SURFACE MOUNT FAST SWITCHING DIODE
 BAV20WS-7 Diodes, Inc. SURFACE MOUNT FAST SWITCHING DIODE
 BAV20W-T3 Won-Top Electronics SURFACE MOUNT FAST SWITCHING DIODE
 BAV20WS-7-F Diodes, Inc. Surface Mount Fast Switching Diode
 BAV20WS-T1 Won-Top Electronics SURFACE MOUNT FAST SWITCHING DIODE
 BAV20WS-T3 Won-Top Electronics SURFACE MOUNT FAST SWITCHING DIODE
 BAV21,113 NXP Semiconductors / Philips Semiconductors General purpose diodes - Cd max.: 5 pF; Configuration: single ; IF max: 250 mA; IFSM max: 9 A; IR max: 100@VR=200V nA; IFRM: 625 mA; trr max: 50 ns; VFmax: 1@IF=100mA mV; VR max: 200 V; Package: SOD27 (ALF2); Container: Reel pack axial radial
 BAV21_T26A Fairchild Semiconductor High Voltage General Purpose Diode
 BAV21_T50R Fairchild Semiconductor High Voltage General Purpose Diode; Package: DO-35; No of Pins: 2; Container: Tape & Reel
 BAV21-A52R Philips Semiconductors / NXP Semiconductors General purpose diodes
 BAV21T/R NXP Semiconductors / Philips Semiconductors General purpose diodes - Cd max.: 5 pF; Configuration: single ; IF max: 250 mA; IFSM max: 9 A; IR max: 100@VR=200V nA; IFRM: 625 mA; trr max: 50 ns; VFmax: 1@IF=100mA mV; VR max: 200 V
 BAV21-TAP Vishay Intertechnology, Inc. Switching Diode
 BAV21T/R NXP Semiconductors / Philips Semiconductors General purpose diodes - Cd max.: 5 pF; Configuration: single ; IF max: 250 mA; IFSM max: 9 A; IR max: 100@VR=200V nA; IFRM: 625 mA; trr max: 50 ns; VFmax: 1@IF=100mA mV; VR max: 200 V
 BAV21 BKC International 250 V, 400 mW silicon epitaxial planar diode
 BAV21T/R NXP Semiconductors / Philips Semiconductors General purpose diodes - Cd max.: 5 pF; Configuration: single ; IF max: 250 mA; IFSM max: 9 A; IR max: 100@VR=200V nA; IFRM: 625 mA; trr max: 50 ns; VFmax: 1@IF=100mA mV; VR max: 200 V
 BAV21,133 NXP Semiconductors / Philips Semiconductors General purpose diodes - Cd max.: 5 pF; Configuration: single ; IF max: 250 mA; IFSM max: 9 A; IR max: 100@VR=200V nA; IFRM: 625 mA; trr max: 50 ns; VFmax: 1@IF=100mA mV; VR max: 200 V; Package: SOD27 (ALF2); Container: Ammo pack axial radial taped
 BAV21,143 NXP Semiconductors / Philips Semiconductors General purpose diodes - Cd max.: 5 pF; Configuration: single ; IF max: 250 mA; IFSM max: 9 A; IR max: 100@VR=200V nA; IFRM: 625 mA; trr max: 50 ns; VFmax: 1@IF=100mA mV; VR max: 200 V; Package: SOD27 (ALF2); Container: Ammo pack axial radial taped
 BAV21_NT50A Fairchild Semiconductor High Voltage General Purpose Diode
 BAV21_T50A Fairchild Semiconductor High Voltage General Purpose Diode; Package: DO-35; No of Pins: 2; Container: Ammo
 BAV21WS-7 Diodes, Inc. SURFACE MOUNT FAST SWITCHING DIODE
 BAV21WS-T1 Won-Top Electronics SURFACE MOUNT FAST SWITCHING DIODE
 BAV21WS-T3 Won-Top Electronics SURFACE MOUNT FAST SWITCHING DIODE
 BAV21W Diodes, Inc. SURFACE MOUNT SWITCHING DIODE
 BAV21W-T1 Won-Top Electronics SURFACE MOUNT FAST SWITCHING DIODE
 BAV21W-7 Diodes, Inc. Surface Mount Switching Diode
 BAV21W-T3 Won-Top Electronics SURFACE MOUNT FAST SWITCHING DIODE
 BAV21W-7-F Diodes, Inc. Surface Mount Switching Diode
 BAV22 Mullard Quick Reference Guide 1977/78
 BAV222 Infineon Technologies Diodes for high speed switching applications
 BAV22R Mullard Quick Reference Guide 1977/78
 BAV23,215 NXP Semiconductors / Philips Semiconductors Dual high-voltage switching diodes - Cd max.: 5 pF; Configuration: dual isolated ; IF max: 225 mA; IFSM max: 9 A; IR max: 100@VR=200V nA; IFRM: 625 mA; trr max: 50 ns; VFmax: 1@IF=100mA mV; VR max: 200 V; Package: SOT143B (SOT4); Container: Tape reel smd
 BAV23A Diodes, Inc. SURFACE MOUNT SWITCHING DIODE
 BAV23A-7-F Diodes, Inc. DIODE SWITCHING DUAL COMMON-ANODE 250V 400mA-Io 350mW 50ns-trr SOT-23 3K/REEL
 BAV21WS Diodes, Inc. SURFACE MOUNT FAST SWITCHING DIODE
 BAV23C Diodes, Inc. SURFACE MOUNT SWITCHING DIODE
 BAV23C-7 Diodes, Inc. Surface Mount Switching Diode
 BAV21WS-7-F Diodes, Inc. Surface Mount Fast Switching Diode

BAV23C-7-F Diodes, Inc. DIODE SWITCHING DUAL COMMON-CATHODE 250V 400mA-Io 350mW 50ns-trr SOT-23 3K/REEL

BAV23CLT1G On Semiconductor DUAL CPR CMDTY PBF

BAV23 Philips Semiconductors / NXP Semiconductors General purpose double diode

BAV23,235 NXP Semiconductors / Philips Semiconductors Dual high-voltage switching diodes - Cd max.: 5 pF; Configuration: dual isolated ; IF max: 225 mA; IFSM max: 9 A; IR max: 100@VR=200V nA; IFRM: 625 mA; trr max: 50 ns; VFmax: 1@IF=100mA mV; VR max: 200 V; Package: SOT143B (SOT4); Container: Tape reel smd

BAV23A-7 Diodes, Inc. Surface Mount Switching Diode

BAV23S,215 NXP Semiconductors / Philips Semiconductors Dual high-voltage switching diodes - Cd max.: 5 pF; Configuration: dual series ; IF max: 225 mA; IFSM max: 9 A; IR max: 100@VR=200V nA; IFRM: 625 mA; trr max: 50 ns; VFmax: 1@IF=100mA mV; VR max: 200 V; Package: SOT23 (TO-236AB); Container: Tape reel smd

BAV23S Continental Device India Limited SILICON PLANAR EPITAXIAL HIGH-SPEED DIODE

BAV23S,235 NXP Semiconductors / Philips Semiconductors Dual high-voltage switching diodes - Cd max.: 5 pF; Configuration: dual series ; IF max: 225 mA; IFSM max: 9 A; IR max: 100@VR=200V nA; IFRM: 625 mA; trr max: 50 ns; VFmax: 1@IF=100mA mV; VR max: 200 V; Package: SOT23 (TO-236AB); Container: Tape reel smd

BAV23S_NL Fairchild Semiconductor High Voltage General Purpose Diode

BAV23S-7 Diodes, Inc. Surface Mount Switching Diode

BAV23T/R NXP Semiconductors / Philips Semiconductors Dual high-voltage switching diodes - Cd max.: 5 pF; Configuration: dual isolated ; IF max: 225 mA; IFSM max: 9 A; IR max: 100@VR=200V nA; IFRM: 625 mA; trr max: 50 ns; VFmax: 1@IF=100mA mV; VR max: 200 V

BAV23S-7-F Diodes, Inc. DIODE SWITCHING DUAL SERIES 250V 400mA-Io 350mW 50ns-trr SOT-23 3K/REEL

BAV23T/R NXP Semiconductors / Philips Semiconductors Dual high-voltage switching diodes - Cd max.: 5 pF; Configuration: dual isolated ; IF max: 225 mA; IFSM max: 9 A; IR max: 100@VR=200V nA; IFRM: 625 mA; trr max: 50 ns; VFmax: 1@IF=100mA mV; VR max: 200 V

BAV26WS PanJit Semiconductors Surface mount switching diode. Power 200 mW. Reverse voltage 75 V. Max average forward current 250 mA.

BAV23ST/R NXP Semiconductors / Philips Semiconductors Dual high-voltage switching diodes - Cd max.: 5 pF; Configuration: dual series ; IF max: 225 mA; IFSM max: 9 A; IR max: 100@VR=200V nA; IFRM: 625 mA; trr max: 50 ns; VFmax: 1@IF=100mA mV; VR max: 200 V

BAV3004 Diodes, Inc. SURFACE MOUNT LOW LEAKAGE DIODE

BAV300 Vishay Intertechnology, Inc. Silicon Epitaxial Planar Diode

BAV3004W Diodes, Inc. SURFACE MOUNT LOW LEAKAGE DIODE

BAV3004W-7-F Diodes, Inc. Surface Mount Low Leakage Diode

BAV3004W-F Diodes, Inc. DIODE ULTRA FAST RECOVERY RECTIFIER 350V 0.22

BAV3004W-7 Diodes, Inc. Surface Mount Low Leakage Diode

BAV300-TR Vishay DIODE SWITCHING 60V 0.25A

BAV3004WS-7 Diodes, Inc. DIODE SWITCHING SINGLE 240V 225mA-Io 200mW 50ns-trr SOD-323 3K/REEL

BAV300-TR3 Vishay DIODE SWITCHING 60V 0.25A

BAV301-TR Vishay Intertechnology, Inc. Switching Diode

BAV301 Diodes, Inc. Short Form Selection Guide

BAV301-GS08 Vishay DIODE SWITCHING 120V 0.25A 2MI

BAV301-TR3 Vishay DIODE SWITCHING 120V 0.25A

BAV302-GS18 Vishay DIODE SWITCHING 200V 0.25A 2MI

BAV302 Diodes, Inc. Short Form Selection Guide

BAV302-GS08 Vishay DIODE SWITCHING 200V 0.25A 2MI

BAV302-TR3 Vishay DIODE SWITCHING 200V 0.25A

BAV303-GS18 Vishay DIODE SWITCHING 250V 0.25A 2MI

BAV302-TR Vishay Intertechnology, Inc. Switching Diode

BAV303-TR Vishay DIODE SWITCHING 250V 0.25A

BAV303 Diodes, Inc. Short Form Selection Guide

BAV45 Central Semiconductor Ledged Silicon Diode General Purpose

BAV303-GS08 Vishay DIODE SWITCHING 250V 0.25A 2MI

BAV46 Mullard Quick Reference Guide 1977/78

BAV47 Texas Instruments Discrete Devices 1978

BW1244X Samsung Electronics DAC, 3.3V 10-Bit 0.5MSPS DAC

BW1244D Samsung Electronics DAC, 3.3V 10-Bit 0.5MSPS DAC

BW1245X Samsung Electronics DAC, 3.3V 8-Bit 3MSPS DAC

BW1249X Samsung Electronics 14 Bit 40 Msps Single DAC

BW1251X Samsung Electronics 0.35 um 12 Bit 500 ksps ADC

BW1254X Samsung Electronics 0.35 um 14 Bit 10 Msps ADC

BW1284X Samsung Electronics 0.35 um 3.3 V 12 Bit 0.32 Msps DAC

BW154G0105K AVX Corporation Film Capacitor

BW154G0105KEN AVX Corporation Film Capacitor

BW154G0105KKB AVX Corporation Film Capacitor

BW154G0105KKC AVX Corporation Film Capacitor

BW154G0105KKE AVX Corporation Film Capacitor

BW154G0105KKH AVX Corporation Film Capacitor

BW154G0105KLG AVX Corporation Film Capacitor

BW154G0155K AVX Corporation Film Capacitor

BW154G0155KK7 AVX Corporation Film Capacitor

BW154G0155KCC AVX Corporation Film Capacitor

BW154G0155KKB AVX Corporation Film Capacitor

BW154G0155KKH AVX Corporation Film Capacitor

BW154G0155KLG AVX Corporation Film Capacitor

BW154G0225KEN	AVX Corporation	Film Capacitor
BW154G0225K	AVX Corporation	Film Capacitor
BW154G0225KKB	AVX Corporation	Film Capacitor
BW154G0225KK7	AVX Corporation	Film Capacitor
BW154G0225KKC	AVX Corporation	Film Capacitor
BW154G0225KKE	AVX Corporation	Film Capacitor
BW154G0225KKH	AVX Corporation	Film Capacitor
BW154G0225KLG	AVX Corporation	Film Capacitor
BW154G0474K	AVX Corporation	Film Capacitor
BW154G0474KEN	AVX Corporation	Film Capacitor
BW154G0474KK7	AVX Corporation	Film Capacitor
BW154G0474KKC	AVX Corporation	Film Capacitor
BW154G0474KKB	AVX Corporation	Film Capacitor
BW154G0474KKE	AVX Corporation	Film Capacitor
BW154G0474KKH	AVX Corporation	Film Capacitor
BW154G0474KLG	AVX Corporation	Film Capacitor
BW154G0684K	AVX Corporation	Film Capacitor
BW154G0684KK7	AVX Corporation	Film Capacitor
BW154G0684KEN	AVX Corporation	Film Capacitor
BW154G0684KKB	AVX Corporation	Film Capacitor
BW154G0684KKC	AVX Corporation	Film Capacitor
BW154G0684KKE	AVX Corporation	Film Capacitor
BW154G0684KKH	AVX Corporation	Film Capacitor
BW154G0684KLG	AVX Corporation	Film Capacitor
BW154G0824K	AVX Corporation	Film Capacitor
BW154G0824KK7	AVX Corporation	Film Capacitor
BW154G0824KKC	AVX Corporation	Film Capacitor
BW154G0824KEN	AVX Corporation	Film Capacitor
BW154G0824KKB	AVX Corporation	Film Capacitor
BW154G0824KKH	AVX Corporation	Film Capacitor
BW154G0824KKE	AVX Corporation	Film Capacitor
BW2006L	Samsung Electronics	PLL, 100MHz-500MHz FSPLL
BW154G0824KLG	AVX Corporation	Film Capacitor
BW2010AGP	Samsung Electronics	Frequency Doublers
BW2010D	Samsung Electronics	DAC, 8-Bit 250MSPS DAC
BW2010P	Samsung Electronics	25 MHz - 250 MHz FSPLL Frequency Synthesizer
BW2017X	Samsung Electronics	0.35 um 3 MHz - 25 MHz FSPLL Frequency Synthesizer
BW2S-D	Panduit Corp.	CABLE ACCESSORIES TIES NYLON 6/6 NATURAL
BW24	Bourns, Inc.	PNP SILICON POWER DARLINGTONS
BW33LT1	On Semiconductor	TRANS GP BJT NPN 32V 0.1A 3 pin SOT-23 T/R
BW31154	Intel	Interface, Transparent PCI/PCI-X Bridge
BW33LT3	On Semiconductor	TRANS GP BJT NPN 20V 0.1A 3 pin SOT-23
BW33LT1G	On Semiconductor	TRANS GP BJT NPN 32V 0.1A 3 pin SOT-23 T/R
BW33LT3G	On Semiconductor	TRANS GP BJT NPN 20V 0.1A 3 pin SOT-23
BW-40N100W	Mini-Circuits	N/A
BW4104X	Samsung Electronics	LVDS Receiver
BW-40N100W	Mini-Circuits	N/A
BWD0515	Power-One	DUAL OUTPUT, 2.5 WATT
BWD1205	International Power Devices, Inc.	BW Series of 2.5 to 3.0 Watt DC/DC Converters
BWD1205I	International Power Devices, Inc.	BW Series of 2.5 to 3.0 Watt DC/DC Converters
BWD1212	International Power Devices, Inc.	BW Series of 2.5 to 3.0 Watt DC/DC Converters
BWD1215	International Power Devices, Inc.	BW Series of 2.5 to 3.0 Watt DC/DC Converters
BWD1215I	International Power Devices, Inc.	BW Series of 2.5 to 3.0 Watt DC/DC Converters
BWD2405	International Power Devices, Inc.	BW Series of 2.5 to 3.0 Watt DC/DC Converters
BWD2405G	Power-One	DC-DC Converter: (18 to 36) V to (-5/5) V
BWD2405I	International Power Devices, Inc.	BW Series of 2.5 to 3.0 Watt DC/DC Converters
BWD	Power-One	DUAL OUTPUT, 2.5 WATT
BWD0515G	Power-One	DC-DC Converter: (4.5 to 9) V to (-15/15) V
BWD1205G	Power-One	DC-DC Converter: (9 to 18) V to (-5/5) V
BWD1212G	Power-One	DC-DC Converter: (9 to 18) V to (-12/12) V
BWD2412	International Power Devices, Inc.	BW Series of 2.5 to 3.0 Watt DC/DC Converters
BWD1212I	International Power Devices, Inc.	BW Series of 2.5 to 3.0 Watt DC/DC Converters
BWD2412G	Power-One	DC-DC Converter: (18 to 36) V to (-12/12) V
BWD2412I	International Power Devices, Inc.	BW Series of 2.5 to 3.0 Watt DC/DC Converters
BWD2415I	International Power Devices, Inc.	BW Series of 2.5 to 3.0 Watt DC/DC Converters
BWD2415	International Power Devices, Inc.	BW Series of 2.5 to 3.0 Watt DC/DC Converters
BWD4805	International Power Devices, Inc.	BW Series of 2.5 to 3.0 Watt DC/DC Converters
BWD4805G	Power-One	DC-DC Converter: (36 to 72) V to (-5/5) V
BWD2415G	Power-One	DC-DC Converter: (18 to 36) V to (-15/15) V

BWD4805I	International Power Devices, Inc.	BW Series of 2.5 to 3.0 Watt DC/DC Converters
BWD4812G	Power-One	DC-DC Converter: (36 to 72) V to (-12/12) V
BWD4812	International Power Devices, Inc.	BW Series of 2.5 to 3.0 Watt DC/DC Converters
BWD4812I	International Power Devices, Inc.	BW Series of 2.5 to 3.0 Watt DC/DC Converters
BWD4815	International Power Devices, Inc.	BW Series of 2.5 to 3.0 Watt DC/DC Converters
BWD4815G	Power-One	DC-DC Converter: (36 to 72) V to (-15/15) V
BWD4815I	International Power Devices, Inc.	BW Series of 2.5 to 3.0 Watt DC/DC Converters
BWD505	International Power Devices, Inc.	BW Series of 2.5 to 3.0 Watt DC/DC Converters
BWD505I	International Power Devices, Inc.	BW Series of 2.5 to 3.0 Watt DC/DC Converters
BWD512	International Power Devices, Inc.	BW Series of 2.5 to 3.0 Watt DC/DC Converters
BWD512I	International Power Devices, Inc.	BW Series of 2.5 to 3.0 Watt DC/DC Converters
BWD515	International Power Devices, Inc.	BW Series of 2.5 to 3.0 Watt DC/DC Converters
BWDM141080D1211	OPLINK Communications	Band Wavelength Division Multiplexer
BWD515G	Power-One	BWD SERIES - DUAL OUTPUT: 2.5 WATT
BWDM141080D1213	OPLINK Communications	Band Wavelength Division Multiplexer
BWDM141080D1214	OPLINK Communications	Band Wavelength Division Multiplexer
BWD515I	International Power Devices, Inc.	BW Series of 2.5 to 3.0 Watt DC/DC Converters
BWDM141080D1212	OPLINK Communications	Band Wavelength Division Multiplexer
BWDM141080D1217	OPLINK Communications	Band Wavelength Division Multiplexer
BWDM141080D1218	OPLINK Communications	Band Wavelength Division Multiplexer
BWDM141080D1215	OPLINK Communications	Band Wavelength Division Multiplexer
BWDM141080D121A	OPLINK Communications	Band Wavelength Division Multiplexer
BWDM141080D1216	OPLINK Communications	Band Wavelength Division Multiplexer
BWDM141080D1221	OPLINK Communications	Band Wavelength Division Multiplexer
BWDM141080D1222	OPLINK Communications	Band Wavelength Division Multiplexer
BWDM141080D1223	OPLINK Communications	Band Wavelength Division Multiplexer
BWDM141080D1226	OPLINK Communications	Band Wavelength Division Multiplexer
BWDM141080D1227	OPLINK Communications	Band Wavelength Division Multiplexer
BWDM141080D1228	OPLINK Communications	Band Wavelength Division Multiplexer
BWDM141080D122A	OPLINK Communications	Band Wavelength Division Multiplexer
BWDM141080D1251	OPLINK Communications	Band Wavelength Division Multiplexer
BWDM141080D1252	OPLINK Communications	Band Wavelength Division Multiplexer
BWDM141080D1253	OPLINK Communications	Band Wavelength Division Multiplexer
BWDM141080D1254	OPLINK Communications	Band Wavelength Division Multiplexer
BWDM141080D1255	OPLINK Communications	Band Wavelength Division Multiplexer
BWDM141080D1256	OPLINK Communications	Band Wavelength Division Multiplexer
BWDM141080D1257	OPLINK Communications	Band Wavelength Division Multiplexer
BWDM141080D1258	OPLINK Communications	Band Wavelength Division Multiplexer
BWDM141080D1259	OPLINK Communications	Band Wavelength Division Multiplexer
BWDM141080D125A	OPLINK Communications	Band Wavelength Division Multiplexer
BWDM141080M1212	OPLINK Communications	Band Wavelength Division Multiplexer
BWDM141080M1211	OPLINK Communications	Band Wavelength Division Multiplexer
BWDM141080M1213	OPLINK Communications	Band Wavelength Division Multiplexer
BWDM141080M1214	OPLINK Communications	Band Wavelength Division Multiplexer
BWDM141080M1215	OPLINK Communications	Band Wavelength Division Multiplexer
BWDM141080M1216	OPLINK Communications	Band Wavelength Division Multiplexer
BWDM141080M1219	OPLINK Communications	Band Wavelength Division Multiplexer
BWDM141080M121A	OPLINK Communications	Band Wavelength Division Multiplexer
BWDM141080M1223	OPLINK Communications	Band Wavelength Division Multiplexer
BWDM141080M1224	OPLINK Communications	Band Wavelength Division Multiplexer
BWDM141080M1225	OPLINK Communications	Band Wavelength Division Multiplexer
BWDM141080M1227	OPLINK Communications	Band Wavelength Division Multiplexer
BWDM141080M1228	OPLINK Communications	Band Wavelength Division Multiplexer
BWDM141080M1229	OPLINK Communications	Band Wavelength Division Multiplexer
BWDM141080M122A	OPLINK Communications	Band Wavelength Division Multiplexer
BWDM141080M1252	OPLINK Communications	Band Wavelength Division Multiplexer
BWDM141080M1254	OPLINK Communications	Band Wavelength Division Multiplexer
BWDM141080M1253	OPLINK Communications	Band Wavelength Division Multiplexer
BWDM141080M1255	OPLINK Communications	Band Wavelength Division Multiplexer
BWDM141080M1256	OPLINK Communications	Band Wavelength Division Multiplexer
BWDM141080M1257	OPLINK Communications	Band Wavelength Division Multiplexer
BWDM141080M1258	OPLINK Communications	Band Wavelength Division Multiplexer
BWDM141080M1259	OPLINK Communications	Band Wavelength Division Multiplexer
BWDM141080M125A	OPLINK Communications	Band Wavelength Division Multiplexer
BWDM360H31011	JDS Uniphase	1536/1554 nm 3-Port Bandpass Wavelength Division Multiplexer
BWDM360H31010	JDS Uniphase	1536/1554 nm 3-Port Bandpass Wavelength Division Multiplexer
BWDM360H31012	JDS Uniphase	1536/1554 nm 3-Port Bandpass Wavelength Division Multiplexer
BWDM360H31013	JDS Uniphase	1536/1554 nm 3-Port Bandpass Wavelength Division Multiplexer
BWDM360H31014	JDS Uniphase	1536/1554 nm 3-Port Bandpass Wavelength Division Multiplexer

BWF11	N/A	N-Channel Silicon FETS
BWL-2B1A01	Bright LED	InGaN Flip chip White Efficient heat transfer.
BWL-2B1A01-H1	Bright LED	1W AllnGaN White High lumen output Efficient heat transfer.
BWL-2B1B01	Bright LED	1W AllnGaN Blue High lumen output Efficient heat transfer.
BWL-2B1B01-H1	Bright LED	1W AllnGaN Blue Low power consumption Efficient heat transfer.
BWL-2B1G01	Bright LED	1W InGaN Flip chip Green Low power consumption
BWL-2B1K01	Bright LED	1W AlGaInP Yellow Low power consumption.
BWL-2B1G01-H1	Bright LED	1W AllnGaN Green Low power consumption.
BWL-2B1K01-H1	Bright LED	1W AlGaInP Yellow Low power consumption.
BWL-2B1R01	Bright LED	1W AlGaInP Face up chip Red Low power consumption.
BWL-3A4A01H	Bright LED	12VDC 4W AllnGaN White Low power consumption.
BWL-2B1R01-H1	Bright LED	1W AlGaInP Red Low power consumption.
BWL-3A4A01H-H1	Bright LED	12VDC 4W AllnGaN White Low power consumption.
BW-N10W5	Mini-Circuits	Attenuator, Precision Fixed Attenuators, 5W 1 To 40 Db, Dc To 18GHz
BW-N10W5	Mini-Circuits	Attenuator, Precision Fixed Attenuators, 5W 1 To 40 Db, Dc To 18GHz
BW-N12W5	Mini-Circuits	Attenuator, Precision Fixed Attenuators, 5W 1 To 40 Db, Dc To 18GHz
BW-N12W5	Mini-Circuits	Attenuator, Precision Fixed Attenuators, 5W 1 To 40 Db, Dc To 18GHz
BW-N15W5	Mini-Circuits	Attenuator, Precision Fixed Attenuators, 5W 1 To 40 Db, Dc To 18GHz
BW-N1W5	Mini-Circuits	Attenuator, Precision Fixed Attenuators, 5W 1 To 40 Db, Dc To 18GHz
BW-N20W5	Mini-Circuits	Attenuator, Precision Fixed Attenuators, 5W 1 To 40 Db, Dc To 18GHz
BW-N1W5	Mini-Circuits	Attenuator, Precision Fixed Attenuators, 5W 1 To 40 Db, Dc To 18GHz
BW-N2W5	Mini-Circuits	Attenuator, Precision Fixed Attenuators, 5W 1 To 40 Db, Dc To 18GHz
BW-N20W5	Mini-Circuits	Attenuator, Precision Fixed Attenuators, 5W 1 To 40 Db, Dc To 18GHz
BW-N30W5	Mini-Circuits	PRECISION FIXED ATTENUATOR
BW-N2W5	Mini-Circuits	Attenuator, Precision Fixed Attenuators, 5W 1 To 40 Db, Dc To 18GHz
BW-N30W5	Mini-Circuits	PRECISION FIXED ATTENUATOR
BW-N3W5	Mini-Circuits	Attenuator, Precision Fixed Attenuators, 5W 1 To 40 Db, Dc To 18GHz
BW-N40W5	Mini-Circuits	Attenuator, Precision Fixed Attenuators, 5W 1 To 40 Db, Dc To 18GHz
BW-N3W5	Mini-Circuits	Attenuator, Precision Fixed Attenuators, 5W 1 To 40 Db, Dc To 18GHz
BW-N40W5	Mini-Circuits	Attenuator, Precision Fixed Attenuators, 5W 1 To 40 Db, Dc To 18GHz
BW-N4W5	Mini-Circuits	Attenuator, Precision Fixed Attenuators, 5W 1 To 40 Db, Dc To 18GHz
BW-N5W5	Mini-Circuits	Attenuator, Precision Fixed Attenuators, 5W 1 To 40 Db, Dc To 18GHz
BW-N5W5	Mini-Circuits	Attenuator, Precision Fixed Attenuators, 5W 1 To 40 Db, Dc To 18GHz
BW-N6W5	Mini-Circuits	Attenuator, Precision Fixed Attenuators, 5W 1 To 40 Db, Dc To 18GHz
BW-N6W5	Mini-Circuits	Attenuator, Precision Fixed Attenuators, 5W 1 To 40 Db, Dc To 18GHz
BW-N7W5	Mini-Circuits	Attenuator, Precision Fixed Attenuators, 5W 1 To 40 Db, Dc To 18GHz
BW-N8W5	Mini-Circuits	Attenuator, Precision Fixed Attenuators, 5W 1 To 40 Db, Dc To 18GHz
BW-N9W5	Mini-Circuits	Attenuator, Precision Fixed Attenuators, 5W 1 To 40 Db, Dc To 18GHz
BW-N8W5	Mini-Circuits	Attenuator, Precision Fixed Attenuators, 5W 1 To 40 Db, Dc To 18GHz
BWP-12/105-D5	Datel, Inc.	DC-DC Converter, (4.5 to 9) V to (-12 12) V
BW-N9W5	Mini-Circuits	Attenuator, Precision Fixed Attenuators, 5W 1 To 40 Db, Dc To 18GHz
BWP-12/125-D48	Datel, Inc.	DC-DC Converter, (18 to 72) V to (-12 12) V
BWP-12/125-D12	Datel, Inc.	DC-DC Converter, (9 to 18) V to (-12 12) V
BWP-12/125-D48	Datel, Inc.	DC-DC Converter, (18 to 72) V to (-12 12) V
BWP-12/125-D12	Datel, Inc.	DC-DC Converter, (9 to 18) V to (-12 12) V
BWP-12/105-D5	Datel, Inc.	DC-DC Converter, (4.5 to 9) V to (-12 12) V
BWP-15/100-D48	Datel, Inc.	DC-DC Converter, (18 to 72) V to (-15 15) V
BWP-15/100-D12	Datel, Inc.	DC-DC Converter, (9 to 18) V to (-15 15) V
BWP-15/100-D12	Datel, Inc.	DC-DC Converter, (9 to 18) V to (-15 15) V
BWP-15/85-D5	Datel, Inc.	DC-DC Converter, (4.5 to 9) V to (-15 15) V
BWP-15/85-D5	Datel, Inc.	DC-DC Converter, (4.5 to 9) V to (-15 15) V
BWP-15/100-D48	Datel, Inc.	DC-DC Converter, (18 to 72) V to (-15 15) V
BWP-5/250-D12	Datel, Inc.	DC-DC Converter, (9 to 18) V to (-5 / 5) V
BWP-5/250-D12	Datel, Inc.	DC-DC Converter, (9 to 18) V to (-5 / 5) V
BWP-5/250-D48	Datel, Inc.	DC-DC Converter, (18 to 72) V to (-5 / 5) V
BWP-5/250-D48	Datel, Inc.	DC-DC Converter, (18 to 72) V to (-5 / 5) V
BWR-12/125-D12	Datel, Inc.	DC-DC Converter, (9 to 18) V to (-12 12) V
BWR-12/105-D5	Datel, Inc.	DC-DC Converter, (4.5 to 9) V to (-12 12) V
BWR-12/125-D48	Datel, Inc.	DC-DC Converter, (18 to 72) V to (-12 12) V
BWR-12/210-D48	C&D Technologies, Inc.	DC to DC Converter, Miniature, 5W, DC/DC Converters
BWR-12/210-D24	Datel, Inc.	DC-DC Converter, (18 to 36) V to (-12 12) V
BWR-12/335-D5A	Datel, Inc.	DC-DC Converter, (4.7 to 7.25) V to (-12 12) V
BWR-12/415-D48A	Datel, Inc.	DC-DC Converter, (18 to 72) V to (-12 12) V
BWR-12/415-D12A	Datel, Inc.	DC-DC Converter, (9 to 18) V to (-12 12) V
BWR-12/725-D12A	Datel, Inc.	DC-DC Converter, (10 to 18) V to (-12 12) V
BWR-12/625-D5A	Datel, Inc.	DC-DC Converter, (4.7 to 7.5) V to (12) V
BUS-61570-300Z	Data Device Corporation	MIL-STD-1553B Notice 2 Advanced Integrated MUX Hybrids with Enhanced RT Features (AIM-HYer)
BUS-61570-310	Data Device Corporation	MIL-STD-1553B Notice 2 Advanced Integrated MUX Hybrids with Enhanced RT Features (AIM-HYer)
BUS-61570-310L	Data Device Corporation	MIL-STD-1553B Notice 2 Advanced Integrated MUX Hybrids with Enhanced RT Features (AIM-HYer)

BUS-61570-850Y	Data Device Corporation	MIL-STD-1553B Notice 2 Advanced Integrated MUX Hybrids with Enhanced RT Features (AIM-HYer)
BUS-61570-850Z	Data Device Corporation	MIL-STD-1553B Notice 2 Advanced Integrated MUX Hybrids with Enhanced RT Features (AIM-HYer)
BUS-61570-860	Data Device Corporation	MIL-STD-1553B Notice 2 Advanced Integrated MUX Hybrids with Enhanced RT Features (AIM-HYer)
BUS-61570-860K	Data Device Corporation	MIL-STD-1553B Notice 2 Advanced Integrated MUX Hybrids with Enhanced RT Features (AIM-HYer)
BUS-61570-860L	Data Device Corporation	MIL-STD-1553B Notice 2 Advanced Integrated MUX Hybrids with Enhanced RT Features (AIM-HYer)
BUS-61570-860S	Data Device Corporation	MIL-STD-1553B Notice 2 Advanced Integrated MUX Hybrids with Enhanced RT Features (AIM-HYer)
BUS-61570-860Q	Data Device Corporation	MIL-STD-1553B Notice 2 Advanced Integrated MUX Hybrids with Enhanced RT Features (AIM-HYer)
BUS-61570-860W	Data Device Corporation	MIL-STD-1553B Notice 2 Advanced Integrated MUX Hybrids with Enhanced RT Features (AIM-HYer)
BUS-61570-860Y	Data Device Corporation	MIL-STD-1553B Notice 2 Advanced Integrated MUX Hybrids with Enhanced RT Features (AIM-HYer)
BUS-61570-860Z	Data Device Corporation	MIL-STD-1553B Notice 2 Advanced Integrated MUX Hybrids with Enhanced RT Features (AIM-HYer)
BUS-61570-870K	Data Device Corporation	MIL-STD-1553B Notice 2 Advanced Integrated MUX Hybrids with Enhanced RT Features (AIM-HYer)
BUS-61570-870	Data Device Corporation	MIL-STD-1553B Notice 2 Advanced Integrated MUX Hybrids with Enhanced RT Features (AIM-HYer)
BUS-61570-870Q	Data Device Corporation	MIL-STD-1553B Notice 2 Advanced Integrated MUX Hybrids with Enhanced RT Features (AIM-HYer)
BUS-61570-870L	Data Device Corporation	MIL-STD-1553B Notice 2 Advanced Integrated MUX Hybrids with Enhanced RT Features (AIM-HYer)
BUS-61570-870W	Data Device Corporation	MIL-STD-1553B Notice 2 Advanced Integrated MUX Hybrids with Enhanced RT Features (AIM-HYer)
BUS-61570-870S	Data Device Corporation	MIL-STD-1553B Notice 2 Advanced Integrated MUX Hybrids with Enhanced RT Features (AIM-HYer)
BUS-61570-870Z	Data Device Corporation	MIL-STD-1553B Notice 2 Advanced Integrated MUX Hybrids with Enhanced RT Features (AIM-HYer)
BUS-61570-870Y	Data Device Corporation	MIL-STD-1553B Notice 2 Advanced Integrated MUX Hybrids with Enhanced RT Features (AIM-HYer)
BUS-61570-880K	Data Device Corporation	MIL-STD-1553B Notice 2 Advanced Integrated MUX Hybrids with Enhanced RT Features (AIM-HYer)
BUS-61570-880L	Data Device Corporation	MIL-STD-1553B Notice 2 Advanced Integrated MUX Hybrids with Enhanced RT Features (AIM-HYer)
BUS-61570-880	Data Device Corporation	MIL-STD-1553B Notice 2 Advanced Integrated MUX Hybrids with Enhanced RT Features (AIM-HYer)
B65659F0003X023	EPCOS AG	RM Cores
B65659F0001X101	EPCOS AG	RM cores are supplied in sets
B65659F0004X023	EPCOS AG	RM Cores
B65659-F1-X101	Siemens Semiconductors	RM 3, Kern
B65659-F1-X1	Siemens Semiconductors	RM 3, Kern
B65659-F1-X23	Siemens Semiconductors	RM 3, Kern
B65659-F3-X23	Siemens Semiconductors	P-Kerne
B65659-F4-X101	Siemens Semiconductors	P-Kerne
B65659-F4-X23	Siemens Semiconductors	RM 3, Kern
B65661	EPCOS AG	Core and Accessories
B65661D0000R001	EPCOS AG	PM/P/P Cores Halves/EP/TT Cores
B65661D0250A048	EPCOS AG	PM/P/P Cores Halves/EP/TT Cores
B65661D0000R026	EPCOS AG	PM/P/P Cores Halves/EP/TT/PR Cores
B65661D0315A048	EPCOS AG	PM/P/P Cores Halves/EP/TT Cores
B65661D1250J048	EPCOS AG	PM/P/P Cores Halves/EP/TT Cores
B65661D0000R048	EPCOS AG	Accessories, Core, Tape and Reel
B65661D0160A048	EPCOS AG	PM/P/P Cores Halves/EP/TT Cores
B65661D0630A048	EPCOS AG	PM/P/P Cores Halves/EP/TT Cores
B65661-D1250-K26	Siemens Semiconductors	P-Kerne
B65661-D-R1	Siemens Semiconductors	P-Kerne
B65661-D-R26	Siemens Semiconductors	P-Kerne
B65661N0250A048	EPCOS AG	PM/P/P Cores Halves/EP/TT Cores
B65661N0160A048	EPCOS AG	PM/P/P Cores Halves/EP/TT Cores
B65661N0315A048	EPCOS AG	PM/P/P Cores Halves/EP/TT Cores
B65661-T100-A33	Siemens Semiconductors	P-Kerne
B65661N0630A048	EPCOS AG	PM/P/P Cores Halves/EP/TT Cores
B65661-T160-G48	Siemens Semiconductors	P-Kerne
B65661-T315-A48	Siemens Semiconductors	P-Kerne
B65661-T500-A48	Siemens Semiconductors	P-Kerne
B65661-T250-G48	Siemens Semiconductors	P-Kerne
B65661-T63-A1	Siemens Semiconductors	P-Kerne
B65661-T400-A48	Siemens Semiconductors	P-Kerne
B65661W0000R030	EPCOS AG	PM/P/P Cores Halves/EP/TT Cores
B65661W0000Y038	EPCOS AG	PM/P/P Cores Halves/EP/TT Cores
B65661-T630-A48	Siemens Semiconductors	P-Kerne
B65661W0000R087	EPCOS AG	PM/P/P Cores Halves/EP/TT Cores
B65661-W-R67	Siemens Semiconductors	P-Kerne
B65661-W-R30	Siemens Semiconductors	P-Kerne
B65661-W-Y38	Siemens Semiconductors	P-Kerne
B65662-A5000	EPCOS AG	Accessories, Coil former, Insulating washer 1, Tape and Reel
B65662	EPCOS AG	Core and Accessories
B65662-A5002	Siemens Semiconductors	P-Kerne
B65662A50020000	EPCOS AG	PM/P/P Cores Halves/EP/TT/PR Cores
B65662A5000X000	EPCOS AG	PM/P/P Cores Halves/EP/TT Cores
B65662B0000T001	EPCOS AG	PM/P/P Cores Halves/EP/TT Cores
B65662B0000T002	EPCOS AG	PM/P/P Cores Halves/EP/TT/PR Cores
B65662-B-T1	Siemens Semiconductors	P-Kerne
B65662-B-T3	Siemens Semiconductors	P-Kerne

B65662-B-T2 Siemens Semiconductors P-Kerne
 B65665-C4 EPCOS AG Accessories, Spring yoke, made of tinned nickel silver (0,4 mm), with ground terminal, 8 solder terminals
 B65665 EPCOS AG Core and Accessories
 B65669-D9-X1 Siemens Semiconductors P-Kerne
 B65669-D11-X22 Siemens Semiconductors P-Kerne
 B65669-E6-X22 Siemens Semiconductors P-Kerne
 B65669-D7-X22 Siemens Semiconductors P-Kerne
 B65671D0000R026 EPCOS AG PM/P/P Cores Halves/EP/TT/PR Cores
 B65671D0000R048 EPCOS AG Accessories, Core, Tape and Reel
 B65671D0160A033 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65671D0250A048 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65671D0400A048 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65671D0630A048 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65671D0800A048 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65671D1000J048 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65671 EPCOS AG PM/P/P Cores Halves/EP/TT/PR Cores
 B65671D0100A001 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65671-D1000-J26 Siemens Semiconductors P-Kerne
 B65671D0100A033 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65671D0160A048 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65671-D1600-K26 Siemens Semiconductors P-Kerne
 B65671D0315A048 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65671T0100A001 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65671-D-R1 Siemens Semiconductors P-Kerne
 B65671T0100A033 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65671T0160A048 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65671T0250A048 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65671-D-R26 Siemens Semiconductors P-Kerne
 B65671T0400A048 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65671T0630A048 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65671-D-R41 Siemens Semiconductors P-Kerne
 B65671T0160A033 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65671-T100-A1 Siemens Semiconductors P-Kerne
 B65671T0315A048 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65671T0800A048 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65671-T100-A33 Siemens Semiconductors P-Kerne
 B65671-T160-G48 Siemens Semiconductors P-Kerne
 B65671-T160-A33 Siemens Semiconductors P-Kerne
 B65671-T400-A48 Siemens Semiconductors P-Kerne
 B65671-T250-G48 Siemens Semiconductors P-Kerne
 B65671-T630-A48 Siemens Semiconductors P-Kerne
 B65671-T315-G48 Siemens Semiconductors P-Kerne
 B65671-T800-A48 Siemens Semiconductors P-Kerne
 B65671-T63-A1 Siemens Semiconductors P-Kerne
 B65671W0000R030 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65671W0000R087 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65671W0000Y038 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65671-W-R67 Siemens Semiconductors P-Kerne
 B65672-A5002 Siemens Semiconductors P-Kerne
 B65672-B5000 Siemens Semiconductors P-Kerne
 B65671-W-R30 Siemens Semiconductors P-Kerne
 B65672B50000000 EPCOS AG PM/P/P Cores Halves/EP/TT/PR Cores
 B65671-W-Y38 Siemens Semiconductors P-Kerne
 B65672-B-T2 Siemens Semiconductors P-Kerne
 B65672B0000T001 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65672-B-T3 Siemens Semiconductors P-Kerne
 B65672B50000000 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65675B00005X000 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65672-B-T1 Siemens Semiconductors P-Kerne
 B65675-B5 EPCOS AG Accessories, Spring yoke, made of tinned nickel silver (0,4 mm), with ground terminal, 8 solder terminals
 B65679E0002X022 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65679E0003X022 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65679-E2-X101 Siemens Semiconductors P-Kerne
 B65679-E1-X22 Siemens Semiconductors P-Kerne
 B65679-E2-X22 Siemens Semiconductors P-Kerne
 B65679-E3-X22 EPCOS AG Accessories, Tube core with thread and core brake made of GFR polyterephthalate
 B65684A0000R027 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65684A0315A027 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65684-A1600-J27 Siemens Semiconductors PM-Kerne

B65684 EPCOS AG PM 62/49
 B65684A0000R087 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65684-A315-A27 EPCOS AG Accessories, Core for Power Transformer
 B65684A0630A027 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65684-A4000-L27 Siemens Semiconductors PM-Kerne
 B65684-A-R27 EPCOS AG Accessories, Core for Power Transformer
 B65684-A630-A27 EPCOS AG PM 62/49
 B65684-A-R87 EPCOS AG Accessories, Core for Power Transformer
 B65685A1000T001 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65685-A2000 Siemens Semiconductors PM-Kerne
 B65685-A1000-T1 Siemens Semiconductors PM-Kerne
 B65685A2000X000 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65685B1016T001 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65686A0000R027 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65686A0315A027 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65686A0630A027 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65685-B1016-T1 Siemens Semiconductors PM-Kerne
 B65686-A315-A27 EPCOS AG PM 74/59
 B65686 EPCOS AG PM 74/59
 B65686-A630-A27 EPCOS AG PM 74/59
 B65686A0000R087 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65686-A2500-J27 Siemens Semiconductors PM-Kerne
 B65686-A-R27 EPCOS AG PM 74/59
 B65686-A4000-L27 Siemens Semiconductors PM-Kerne
 B65686-A-R87 Siemens Semiconductors PM-Kerne
 B65687-A1000-T1 Siemens Semiconductors PM-Kerne
 B65687A1000T001 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65687A1018T001 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65687-A1018-T1 Siemens Semiconductors PM-Kerne
 B65687A2000X000 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65687-A2000 Siemens Semiconductors PM-Kerne
 B65701D0000R026 EPCOS AG PM/P/P Cores Halves/EP/TT/PR Cores
 B65701D0250A048 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65701D0630A048 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65701D1000A048 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65701-D2000-K26 Siemens Semiconductors P-Kerne
 B65701 EPCOS AG PM/P/P Cores Halves/EP/TT/PR Cores
 B65701D0000R048 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65701D0400A048 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65701-D-R26 Siemens Semiconductors P-Kerne
 B65701T0250A048 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65701-D1250-J26 Siemens Semiconductors P-Kerne
 B65701T0400A048 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65701T0630A048 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65701D2000J048 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65701T1000A048 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65701-T1000-A48 Siemens Semiconductors P-Kerne
 B65701-T630-A48 Siemens Semiconductors P-Kerne
 B65701W0000R030 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65701-T250-G48 Siemens Semiconductors P-Kerne
 B65701W0000Y038 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65701-T400-A48 Siemens Semiconductors P-Kerne
 B65701-W-R30 Siemens Semiconductors P-Kerne
 B65701W0000R087 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65701-W-R67 Siemens Semiconductors P-Kerne
 B65701-W-Y38 Siemens Semiconductors P-Kerne
 B65702A50000000 EPCOS AG PM/P/P Cores Halves/EP/TT/PR Cores
 B65702-A5000 Siemens Semiconductors P-Kerne
 B65702A5000X000 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65702B0000T001 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65702-A5002 Siemens Semiconductors P-Kerne
 B65702-B-T2 Siemens Semiconductors P-Kerne
 B65702-B-T1 Siemens Semiconductors P-Kerne
 B65713A0000R027 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65705B0003X000 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65713A0000R087 EPCOS AG PM/P/P Cores Halves/EP/TT Cores
 B65713-A1000-A27 Siemens Semiconductors PM-Kerne
 B65713-A2500-J27 Siemens Semiconductors PM-Kerne
 B65713 EPCOS AG PM 87/70